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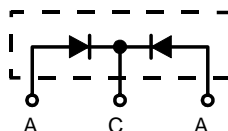


# Common Cathode Fast Recovery Epitaxial Diode (FRED)

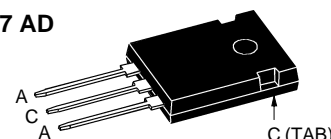
**DSEK 60**

**$I_{FAVM} = 2 \times 30 \text{ A}$**   
 **$V_{RRM} = 600 \text{ V}$**   
 **$t_{rr} = 35 \text{ ns}$**

$V_{RSM}$	$V_{RRM}$	Type
V	V	
640	600	DSEK 60-06A



TO-247 AD



A = Anode, C = Cathode, TAB = Cathode

Symbol	Test Conditions	Maximum Ratings	
$I_{FRMS}$	$T_{VJ} = T_{VJM}$	50	A
$I_{FAVM}$ ①	$T_C = 85^\circ\text{C}$ ; rectangular, $d = 0.5$	30	A
$I_{FRM}$	$t_p < 10 \mu\text{s}$ ; rep. rating, pulse width limited by $T_{VJM}$	375	A
$I_{FSM}$	$T_{VJ} = 45^\circ\text{C}$ ; $t = 10 \text{ ms}$ (50 Hz), sine	300	A
	$t = 8.3 \text{ ms}$ (60 Hz), sine	320	A
	$T_{VJ} = 150^\circ\text{C}$ ; $t = 10 \text{ ms}$ (50 Hz), sine	260	A
	$t = 8.3 \text{ ms}$ (60 Hz), sine	280	A
$I^2t$	$T_{VJ} = 45^\circ\text{C}$ ; $t = 10 \text{ ms}$ (50 Hz), sine	450	A <sup>2</sup> s
	$t = 8.3 \text{ ms}$ (60 Hz), sine	420	A <sup>2</sup> s
	$T_{VJ} = 150^\circ\text{C}$ ; $t = 10 \text{ ms}$ (50 Hz), sine	340	A <sup>2</sup> s
	$t = 8.3 \text{ ms}$ (60 Hz), sine	320	A <sup>2</sup> s
$T_{VJ}$		-40...+150	°C
$T_{VJM}$		150	°C
$T_{stg}$		-40...+150	°C
$P_{tot}$	$T_C = 25^\circ\text{C}$	125	W
$M_d$	Mounting torque	0.8...1.2	Nm
Weight		6	g

## Features

- International standard package JEDEC TO-247 AD
- Planar passivated chips
- Very short recovery time
- Extremely low switching losses
- Low  $I_{RM}$ -values
- Soft recovery behavior
- Epoxy meets UL 94V-0

## Applications

- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

## Advantages

- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching
- Low losses
- Operating at lower temperature or space saving by reduced cooling

Symbol	Test Conditions	Characteristic Values	
		typ.	max.
$I_R$	$T_{VJ} = 25^\circ\text{C}$ $V_R = V_{RRM}$		100 $\mu\text{A}$
	$T_{VJ} = 25^\circ\text{C}$ $V_R = 0.8 \cdot V_{RRM}$		50 $\mu\text{A}$
	$T_{VJ} = 125^\circ\text{C}$ $V_R = 0.8 \cdot V_{RRM}$		7 mA
$V_F$	$I_F = 37 \text{ A}$ ; $T_{VJ} = 150^\circ\text{C}$		1.4 V
	$T_{VJ} = 25^\circ\text{C}$		1.6 V
$V_{To}$	For power-loss calculations only		1.01 V
$r_T$	$T_{VJ} = T_{VJM}$		7.1 m $\Omega$
$R_{thJC}$	0.25		1 K/W
$R_{thCK}$			K/W
$R_{thJA}$			70 K/W
$t_{rr}$	$I_F = 1 \text{ A}$ ; $-di/dt = 100 \text{ A}/\mu\text{s}$ ; $V_R = 30 \text{ V}$ ; $T_{VJ} = 25^\circ\text{C}$	35	50 ns
$I_{RM}$	$V_R = 350 \text{ V}$ ; $I_F = 30 \text{ A}$ ; $-di_F/dt = 240 \text{ A}/\mu\text{s}$ $L \leq 0.05 \mu\text{H}$ ; $T_{VJ} = 100^\circ\text{C}$	10	11 A

①  $I_{FAVM}$  rating includes reverse blocking losses at  $T_{VJM}$ ,  $V_R = 0.8 V_{RRM}$ , duty cycle  $d = 0.5$   
 Data according to IEC 60747 and refer to a single diode unless otherwise stated.  
 IXYS reserves the right to change limits, test conditions and dimensions

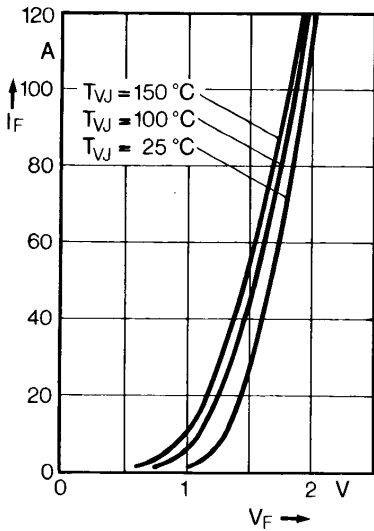


Fig. 1 Forward current versus voltage drop.

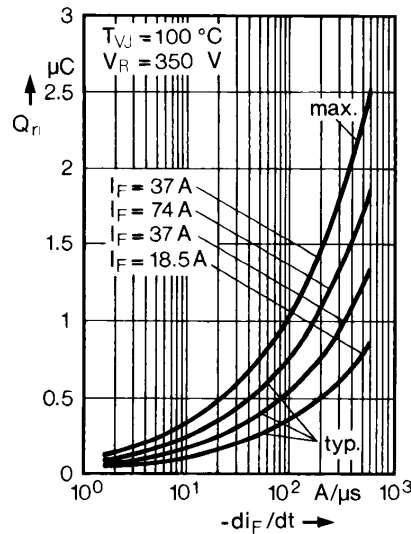


Fig. 2 Recovery charge versus  $-di_F/dt$ .

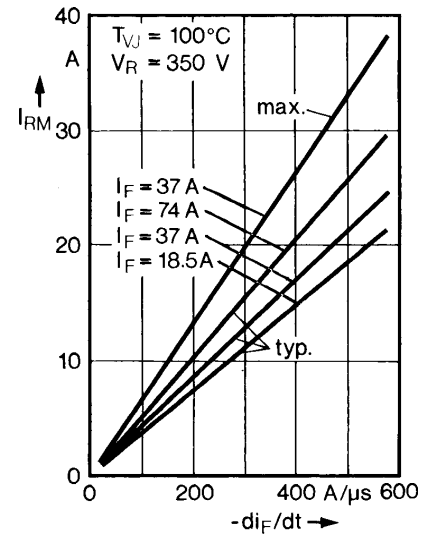


Fig. 3 Peak reverse current versus  $-di_F/dt$ .

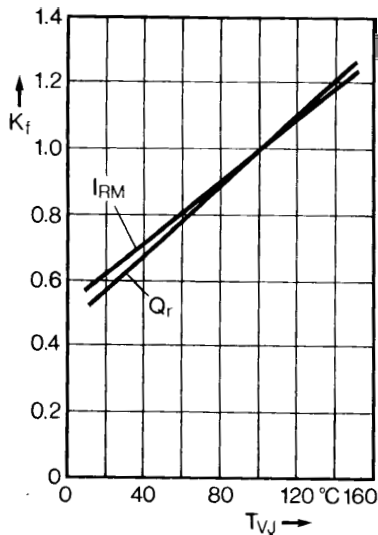


Fig. 4 Dynamic parameters versus junction temperature.

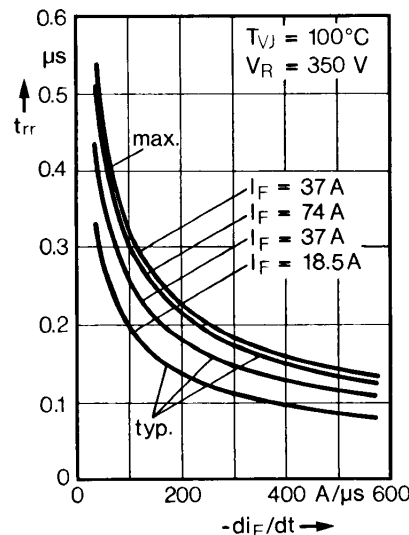


Fig. 5 Recovery time versus  $-di_F/dt$ .

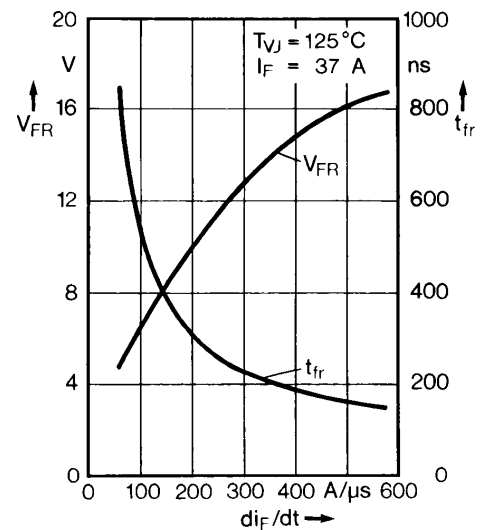


Fig. 6 Peak forward voltage versus  $di_F/dt$ .

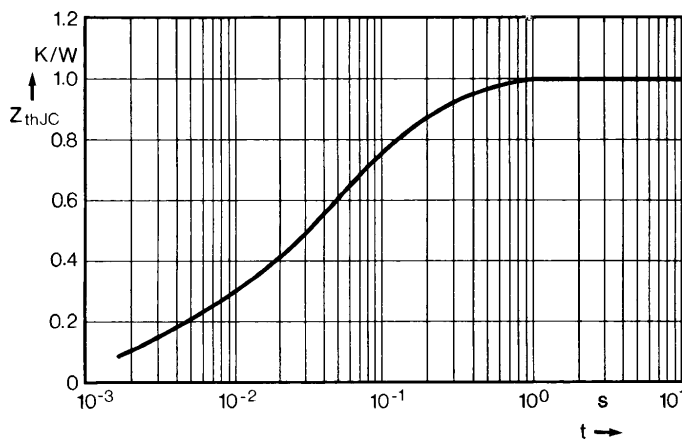
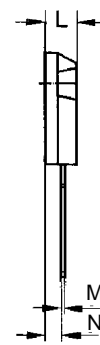
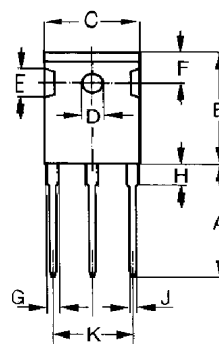


Fig. 7 Transient thermal impedance junction to case.

**Dimensions**



Dim.	Millimeter Min. Max.	Inches Min. Max.
A	19.81 20.32	0.780 0.800
B	20.80 21.46	0.819 0.845
C	15.75 16.26	0.610 0.640
D	3.55 3.65	0.140 0.144
E	4.32 5.49	0.170 0.216
F	5.4 6.2	0.212 0.244
G	1.65 2.13	0.065 0.084
H	- 4.5	- 0.177
J	1.0 1.4	0.040 0.055
K	10.8 11.0	0.426 0.433
L	4.7 5.3	0.185 0.209
M	0.4 0.8	0.016 0.031
N	2.2 2.54	0.087 0.102